

Optoelectronic converter **eoSense**™

Make UWB EM-field measurement in time & frequency domains with optical RX antennas from 10 Hz up to 100 GHz

Optoelectronic converter compliant with eoProbe™ optical RX antennas Constant AF (Antenna Factor) regardless of optical RX antenna position and temperature 4th converter gen. with ultra high EMI shielding usable with both Efield & H-field probes

Optoelectronic converter line covering RF spectrum from low frequency LF model (10 Hz → 50 MHz) up to high frequency HF-25-40 model (25 → 40 GHz) & customized models



Distributed by: Reliant EMC LLC, 408-320-9644/408-916-5750, www.reliantemc.com

Performance specifications						
	Model	Min	Typical	Max	Unit	
Frequency bandwidth (cutoff freq. $f_{\text{low}} \& f_{\text{high}} \pm 10\%$)	LF	10		50M		
	MF		for next release	è		
	HF-0.04-3.2	40M		3.2G		
	HF-0.04-6.4	40M		6.4G	Ш -	
	HF-2.5-18	2.5G		18G	ΠZ	
	HF-18-26.5	18G		26.5G		
	HF-25-40	25G		40G		
	Customized model	f _{low}		f _{high}		
P1dB (1-dB compression point) in Frequency Domain	LF	18	19			
	MF		for next release	è		
	HF-0.04-3.2 & HF-0.04-6.4	19	20		dBm	
	HF-2.5-18	20	22			
	HF-18-26.5 & HF-25-40	15	18			
Output voltage swing in Time Domain	LF	5.0	5.6			
	MF for next release		è			
	HF-0.04-3.2 & HF-0.04-6.4	5.6	6.3		Vpp	
	HF-2.5-18	6.3	8.0			
	HF-18-26.5 & HF-25-40	3.5	5.0			
Output noise spectral density	LF (<i>f</i> > 200 kHz)		-120	-110		
	MF for next release			è		
	HF-0.04-3.2 & HF-0.04-6.4		-110	-100	dBm /H-	
	HF-2.5-18		-110	-100	adm/112	
	HF-18-26.5		-100	-90		
	HF-25-40		-90	-80		
Phase noise with use of any probe eoProbe TM	@10 Hz from carrier			-70	dBc/Hz	
Antenna factor AF for use with EL5-air probe	LF		115	125		
	MF		for next release		dB /m	
	HF-0.04-3.2/6.4		100	110	ud/ III	
	HF-2.5-18 (for <i>f</i> < 10 GHz)		100	110		
Dynamic range in Frequency Domain	LF (<i>f</i> > 200 kHz)	130	140			
	MF for next release		è			
	HF-0.04-3.2/6.4 & HF-2.5-18	120	130		dB.Hz	
	HF-18-26.5	110	120			
	HF-25-40	100	110			

MECHANICAL SPECIFICATIONS					
		Min	Typical	Max	Unit
Dimensions ± 1 mm (cf. Max for overall dimensions)	Width		150	150	
	Depth		450	522	mm
	Height		185	195	
Weight	All models	6.7		7.4	kg
Ingress Protection rating			IP41		
Front panel I/O	 Human Machine Interface 	Interface 4.3" capacitive touchscreen			
	Optical probe	Push-Pu	Ull Diamond HE	-2000	
	3 USB 2.0	Type A	socket		
	4 Signal output (Z = 50 Ω)	SMA or	SMK (2.92 mr	n)	
Rear panel I/O	5 Ethernet	RJ45 sc	ocket		
	6 Earthing stud	POAG-	S6		
	Power entry connector	C14 so	cket		

Front panel







Environmental specifications					
		Min	Typical	Max	Unit
Power supply	Voltage	90		260	VAC
	Frequency	47		63	Hz
	Power		65	130	W
Temperature	Operating	15		30	°C
	Storage	5		40	C
Pressure		690		1075	hPa
Relative humidity Non-condensing				90	%
Storage	Only in its original case in a clean, dry environment				
Cleaning	Use cloth moistened with clean water mixed with < 20% of isopropyl alcohol (only for outer part of connectors)				

Standards compliance			
EMC, emissions	IEC 60601-1-2 4th ed. EN 55032 class B		
	IEC / EN 61000-3-2, class B		
	IEC / EN 61000-3-3, class B		
EMC, immunity	IEC / EN 60601-1-2		
	IEC / EN 61000-4-2, 8kV/6kV perf. criteria A		
	IEC / EN 61000-4-3, 20V/m perf. criteria A		
	IEC / EN 61000-4-4, ± 2kV perf. criteria A		
	IEC / EN 61000-4-5, ± 1kV/± 2kV perf. criteria A		
	IEC / EN 61000-4-6, 20 Vrms perf. criteria A		
Laser safety	IEC / EN 60825-1, class 1		
	IEC / EN 60825-2, class 1		

PACKAGING INFORMATION

	Contents	
Converter	Delivered with a routine test report	
Power cord	with CEE 7/7 plug (Europe, Asia) or with NEMA 5/15 plug (North America, Japon)	
Ground strap	1 m length, 4 mm ² cable cross-section	
Transport box	Triple-wall cardboard with protective foam	
Firmware update	See website https://en.kapteos.com/	
User guide	See website <u>https://en.kapteos.com/</u>	

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Compatible devices and accessories					
Device	Associated data sheet	Use	Outline schematic		
EM-field probe	eoProbe-FT-23.07.pdf	Recommended setup in most cases	eoSense [™] 5 m eoProbe [™] eoPod [™]		
Optical fiber extension cord	eoLink-FT-23.07.pdf	Required setup for measurements over great distances, like outdoor conditions	eoSense [™] Signal OUT eoLink [™] eoProbe [™] eoProbe [™]		
Optical multiplexer	eoSwitch-FT-23.07.pdf	Recommended setup to sequentially connect up to 16 probes	eoSense [™] Signal OUT eoSwitch [™] eoProbe [™] eoProbe [™] eoProbe [™]		
EM-field probe calibration cell	eoCal-FT-23.07.pdf	Required setup for probe calibration in air or in any fluid	eoSense [™] → Signal OUT eoProbe [™] eoCal [™]		

Hardware options, customization and accessories				
Field of activity	lssue	Options and/or accessories		
MRI	Ultra narrowband signals	-3T Ultra narrow external filters for 0.55T, 1.5T, 3T, 4.7T MRI machines		
High Voltage	Partial discharge assessment	-PD External diplexer with two channels: 10 Hz \rightarrow 50 MHz and 2 kHz \rightarrow 50 MHz		
Antonnos	RF spectrum coverage	-DB, -TB Dual-band or triple-band for HF converter only (e.g. 2.5 GHz → 40 GHz)		
Aniennas	Automotive radar characterization	-DC75 76-81 GHz converter with embedded freq. down-conversion to 1-6 GHz		

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SOFTWARE	options	
Option	Function	Requirements
-ASA	E-field strength display through direct control of end customer spectrum analyzer through Ethernet cable.	Recent Automatic Spectrum Analyzer with Ethernet remote control
-AWG+ASA	E-field strength display versus frequency through direct control of both end customer synthesizer & spectrum analyzer through Ethernet cables	Recent Arbitrary Waveform Generator & Automatic Spectrum Analyzer with Ethernet remote control
-CRF	Correction of the Response Flatness of the EM-field measurement system (OEC + EM-field probe) to get a flat response on the frequency range of interest	Factory calibration of the OptoElectronic Converter (OEC)

USEFUL EQUATIONS

 $P_{\rm occ} \rightarrow$ Power delivered by the optoelectronic converter Equation $V_{\rm occ} \rightarrow$ Voltage generated by the optoelectronic converter

Frequency domain	$E [dBV_{RMS}/m] = P_{OEC} [dBm] + AF [dB/m] - 13.01$
Time domain	E [V/m] = V_{OEC} [V] × AF [m ⁻¹]
Conversion of units	$AF [dB/m] = 20 \log_{10}(AF [m^{-1}])$ $E [V_{RMS}/m] = 10^{(E [dBV_{RMS}/m] / 20)}$

Ordering information					
Model	Туре	(Hardware option)	(Accessory)	(Software option)	
eoSense	LF		-PD	-CRF	
	MF		-3T		
	HF-0.04-3.2	-DB-2.5-18		-ASA	
	HF-2.5-18	-TB-18-26.5-25-40		-AWG+ASA	
	HF-75-85	-DC75			

Examples: Optoelectronic converter for 10 Hz-50 MHz frequency range with diplexer for partial discharge assessment and correction of response flatness → eoSense LF-PD-CRF

Optoelectronic converter for 25 GHz-40 GHz frequency range → eoSense HF-25-40

Optoelectronic converter for 40 MHz-18 GHz frequency range in two RF bands with direct control of spectrum analyzer → eoSense HF-0.04-3.2-DB-2.5-18-ASA

Customized optoelectronic converter for 75 GHz-85 GHz frequency range with down conversion to DC-10 GHz

 \rightarrow eoSense HF-75-85-DC75